

an interlayer insulation film formed covering the thin film transistors, the gate lines, and the drain lines;

a plurality of pixel electrodes each connected to the source of the thin film transistor and partially formed on the interlayer insulation film;

a second substrate disposed opposite the first substrate;

a liquid crystal layer arranged between the first and second substrates;

a common electrode formed on the second substrate; and

an orientation control window created in the common electrode; wherein orientation direction of liquid crystal is divided by weak electric fields and/or electric fields in a sloped direction generated by the orientation control window, and the interlayer insulation film has a thickness sufficient to alleviate an influence on the liquid crystal layer from an electric field generated by the thin film transistors, the gate lines, and the drain lines.

28. (Amended) A liquid crystal display, comprising:

a first substrate;

a plurality of gate lines and drain lines formed on the first substrate;

thin film transistors each arranged at an intersection between a corresponding gate line and a corresponding drain line, and having a gate connected to the corresponding gate line, a drain connected to the corresponding drain line, and a source;

an interlayer insulation film formed covering the thin film transistors, the gate lines, and the drain lines;

a plurality of pixel electrodes each connected to the source of the corresponding thin film transistor and partially formed on the interlayer insulation film;

a second substrate disposed opposing the first substrate;

a liquid crystal layer arranged between the first and second substrates;

a common electrode formed on the second substrate; and

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an orientation dividing portion for dividing an orientation direction of liquid crystal by generating weak electric fields and/or electric fields in a sloped direction, wherein the interlayer insulation film has a thickness sufficient to alleviate an influence on the liquid crystal layer from an electric field generated by the thin film transistors, the gate lines, and the drain lines.

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38. (Amended) The liquid crystal display as claimed in claim 37, wherein the interlayer insulation film has a thickness sufficient to alleviate an influence on the liquid crystal layer by an electric field generated by the thin film transistors, the gate lines, and the drain lines.